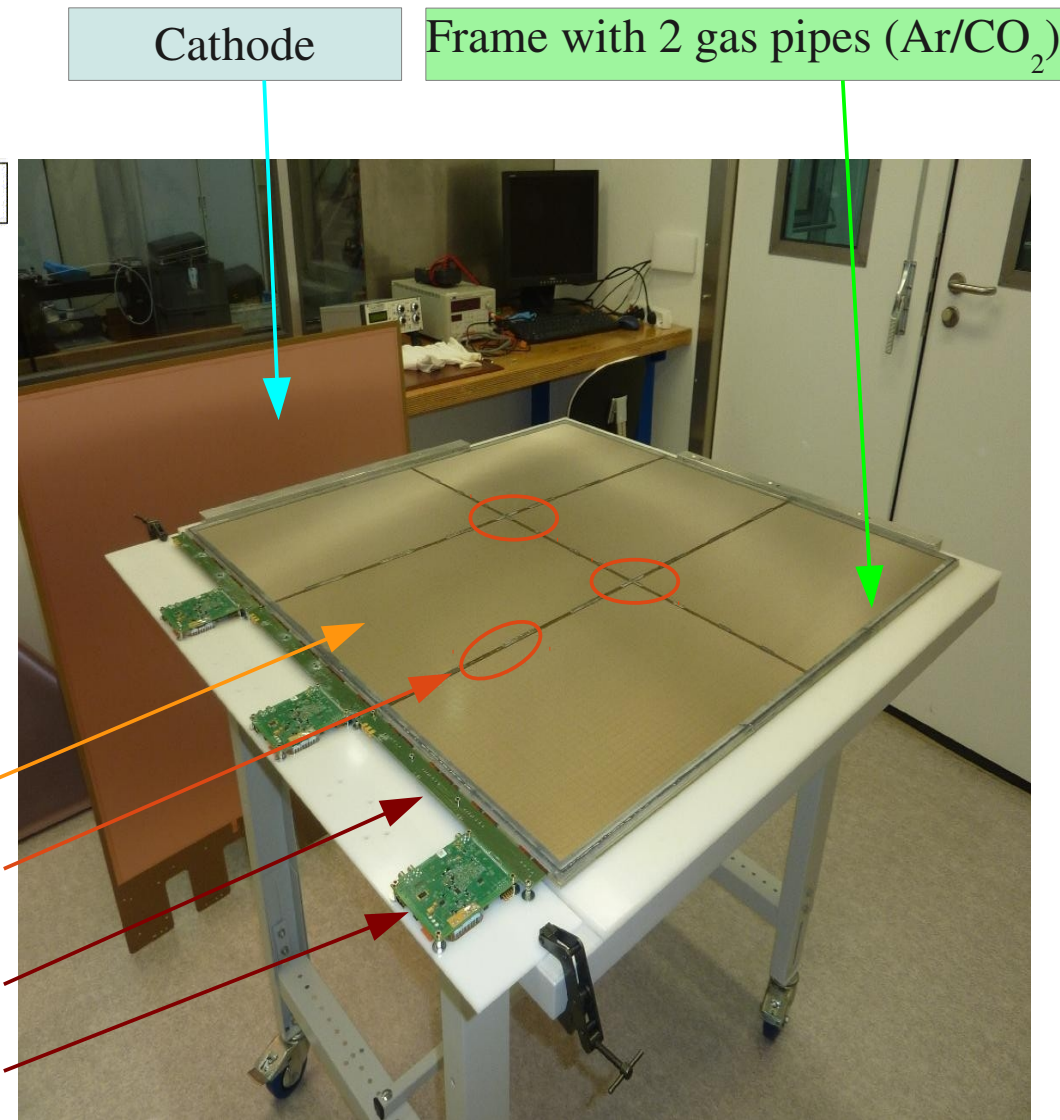
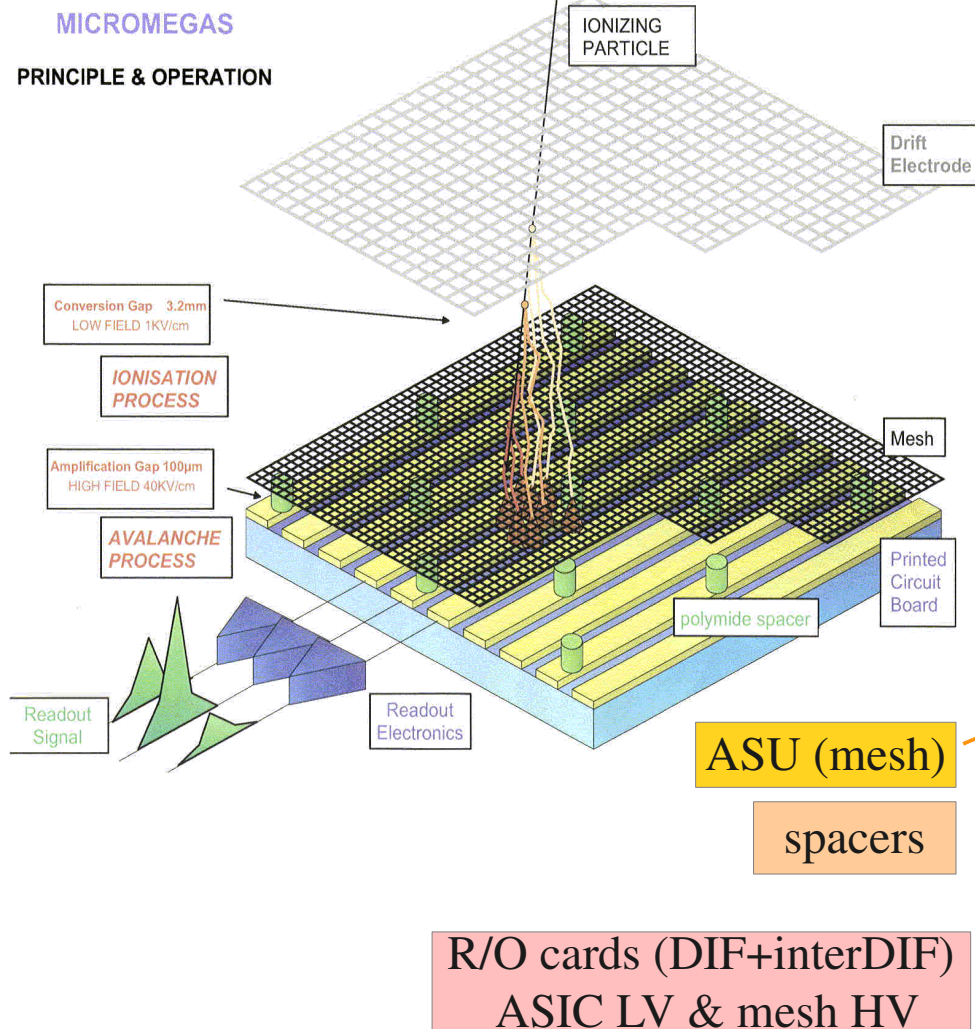


Test beam results of small resistive Micromegas prototypes

*CALICE Collaboration Meeting
September 09-11th 2013
LAPP, Annecy-le-Vieux*

J. Samarati

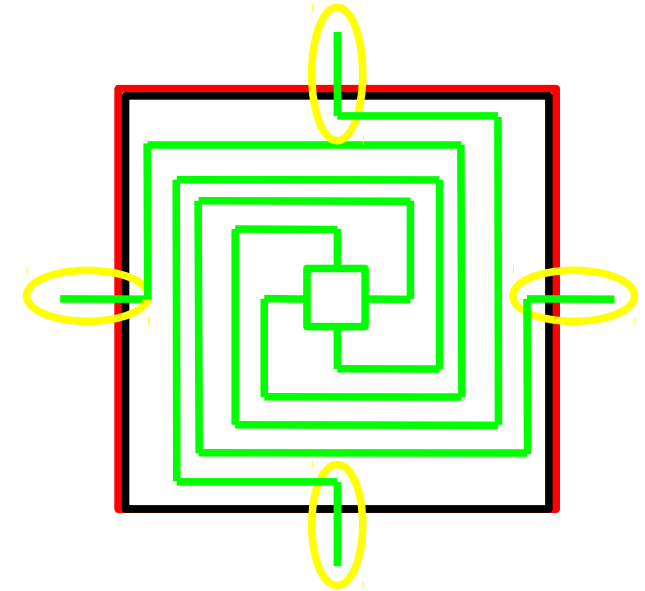
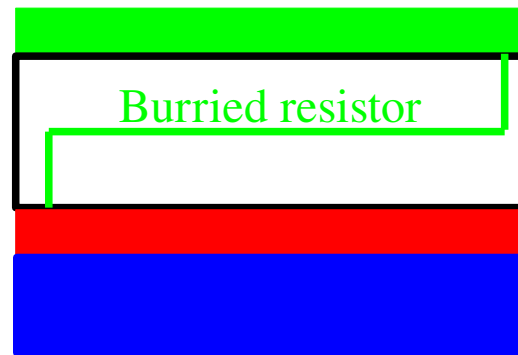
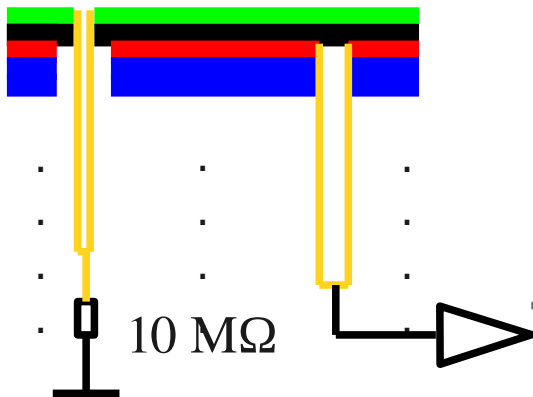
Principle of Micromegas detector



Micromegas → good performances (efficiency, rate capabilities, energy and position resolution)
→ but spark sensitive → introduction of resistive layers

Resistive Micromegas detectors

Beam test goals : Compare performances of $16 \times 16 \text{ cm}^2$ standards and resistive Micromegas (efficiency, multiplicity, rate capabilities, spark rate, threshold...)
Resistive Micromegas : 3 configurations tested



Resistive vias configuration
(independent pad)

Burried resistors configuration
(independent pad)

Resistive lines configuration
(connected pads)

Resistive Micromegas : good sparks protection, simpler and cheaper PCB (than with diodes)
but rate limitation (charge evacuation)

Test beam setup

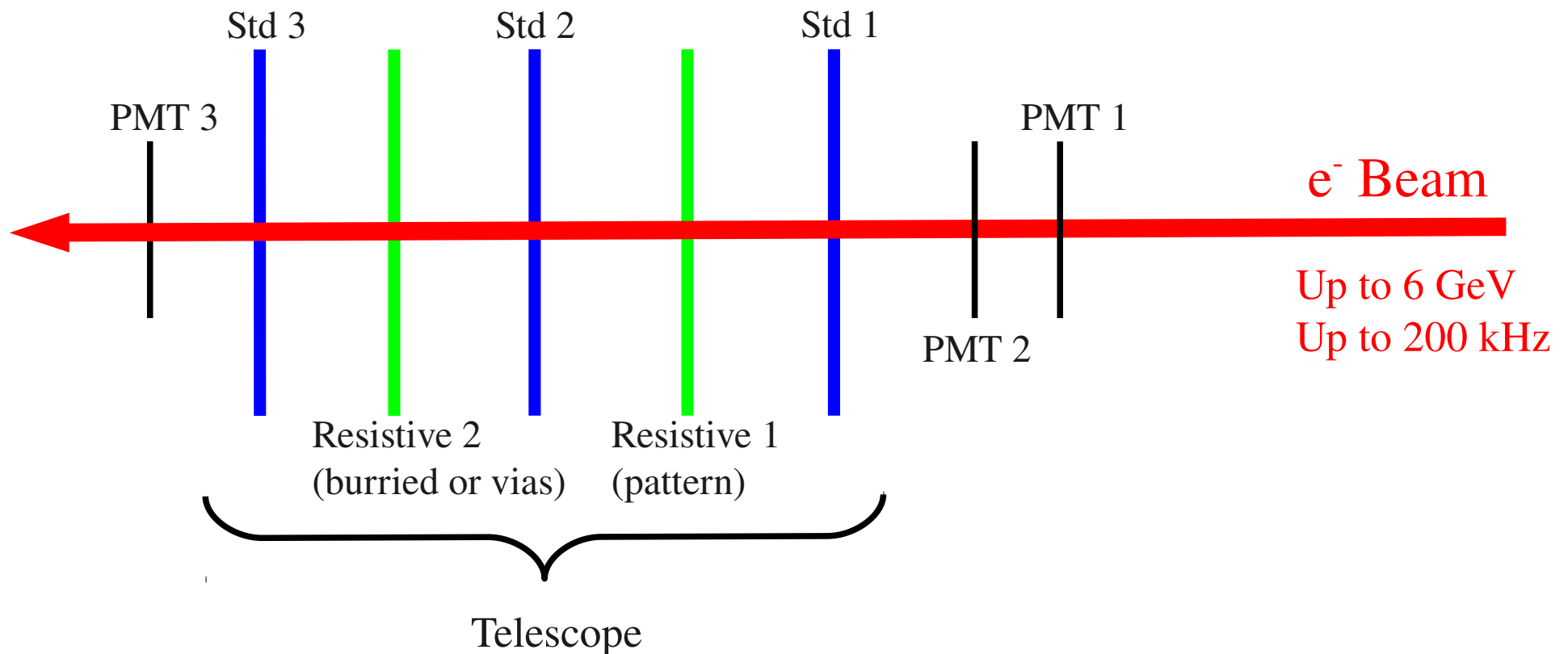
Setup :

3 standards & 3 resistive chambers

Ar/CO₂ gas mixture

Intermediate CALICE DAQ system

Software : LAPP based (Labview, C++ framework)

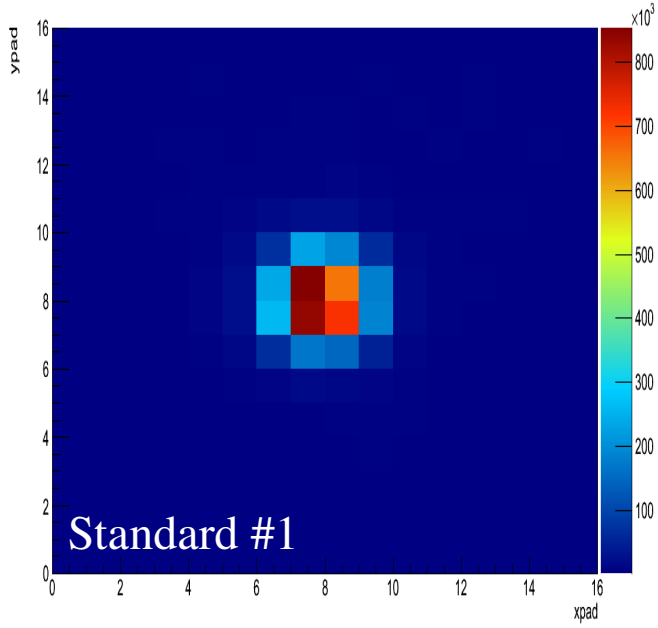


Test beam setup

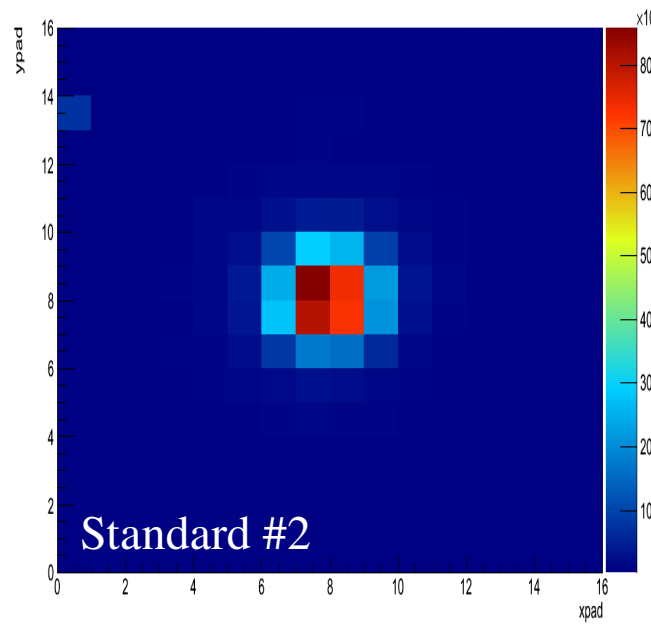


Beam profile

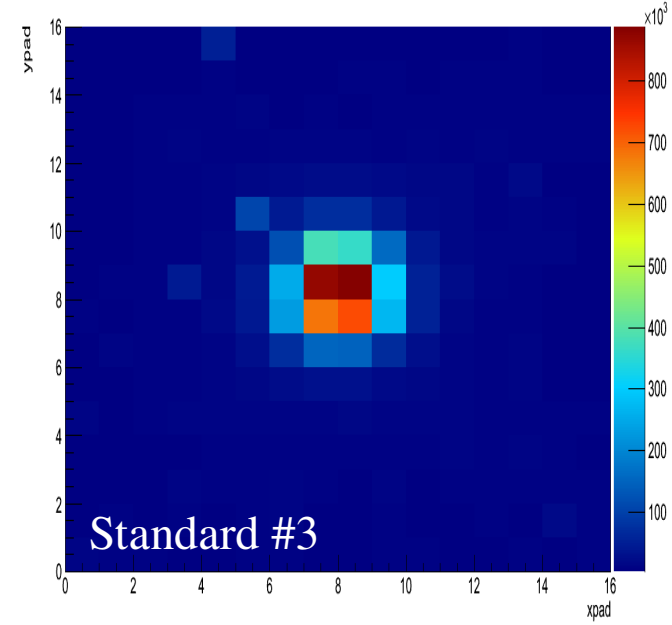
Hit position in chamber 1



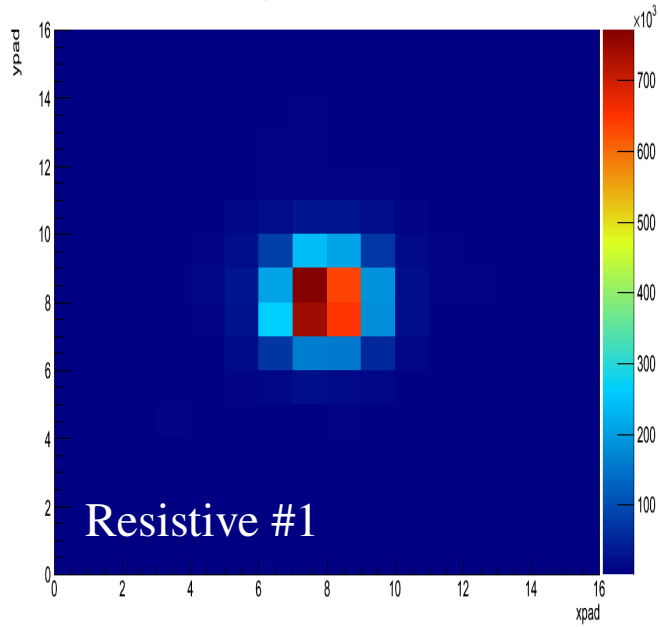
Hit position in chamber 3



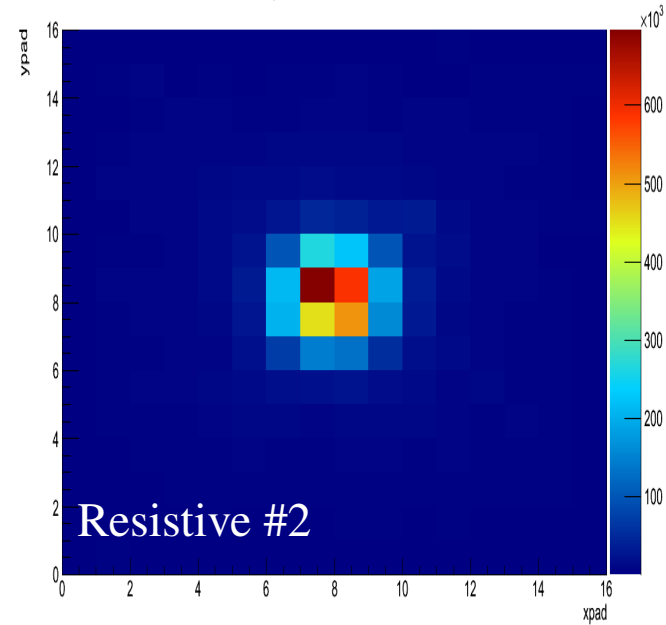
Hit position in chamber 5



Hit position in chamber 2

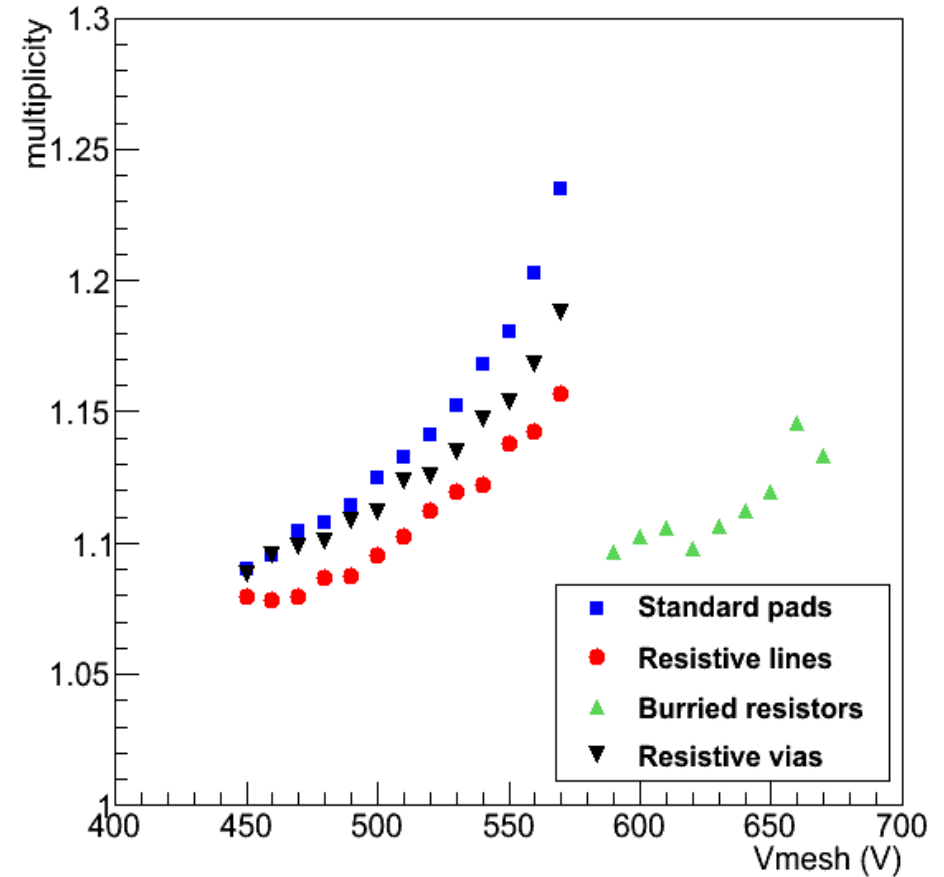
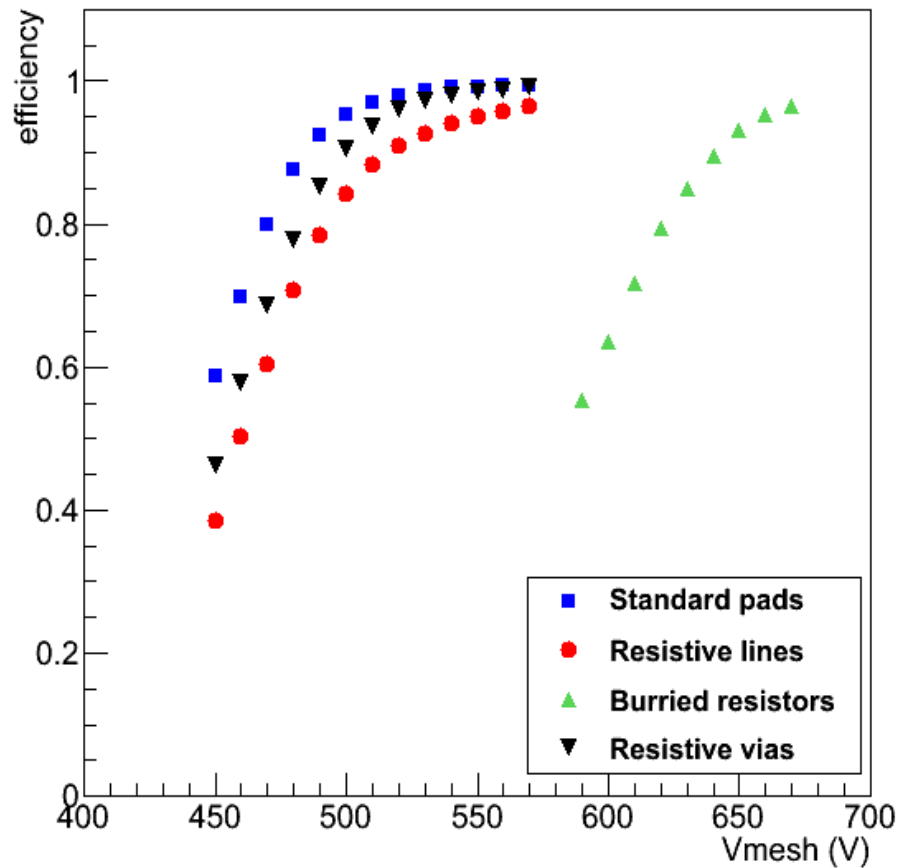


Hit position in chamber 4



Good news → chambers worked @ first beam !!!

Efficiency and multiplicity vs HV mesh

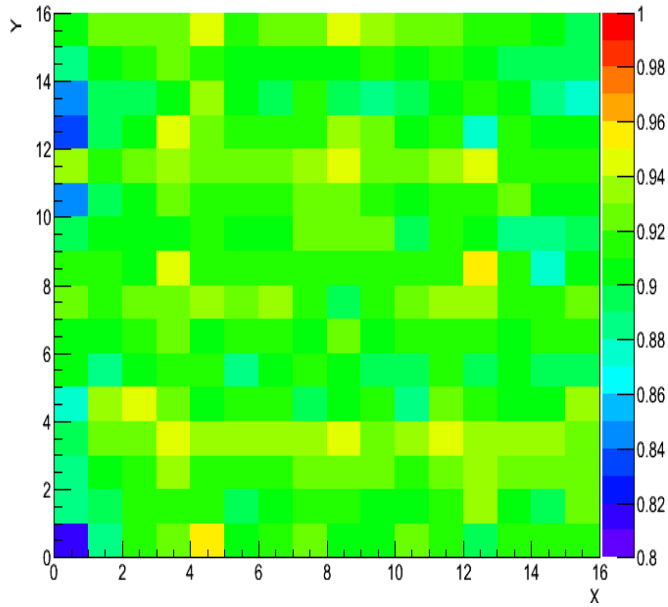


Efficiency $\geq 95\%$ and multiplicity contains $1.03 \leq \text{mult} \leq 1.25$ pad for all chambers

Chamber with burried resistors needs 100 V more than the others \Rightarrow problem in the construction (no contact or bad contacts between resistive layer and R/O pad)

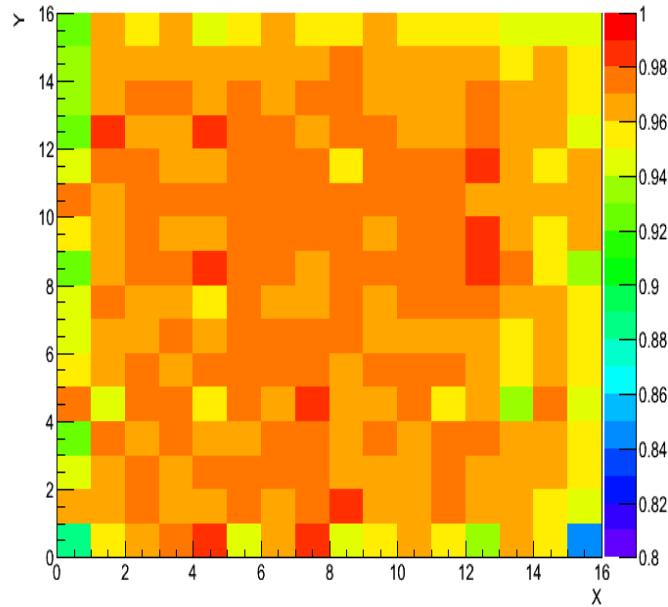
Uniformity of the response

Efficiency map chb2 thr0



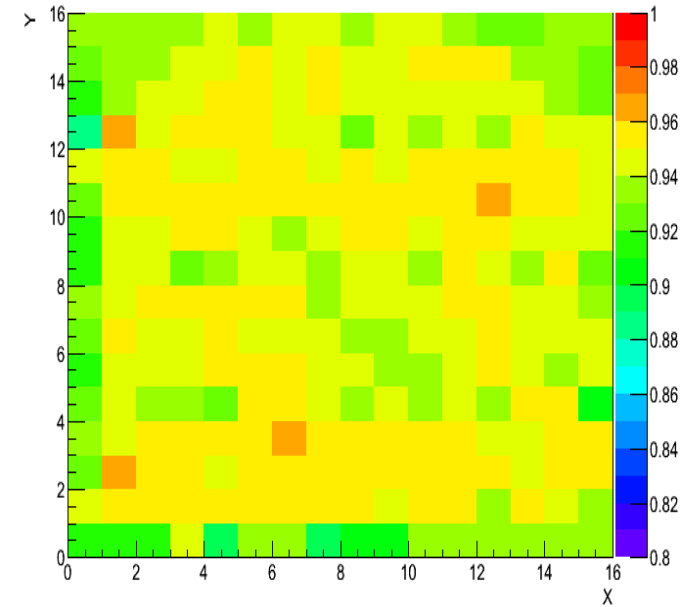
Resistive lines

Efficiency map chb3 thr0

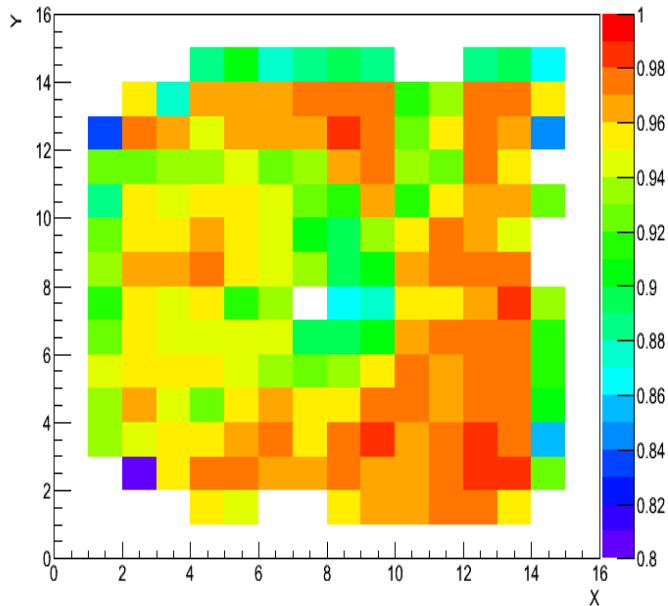


Standard

Efficiency map chb4 thr0



Resistive vias

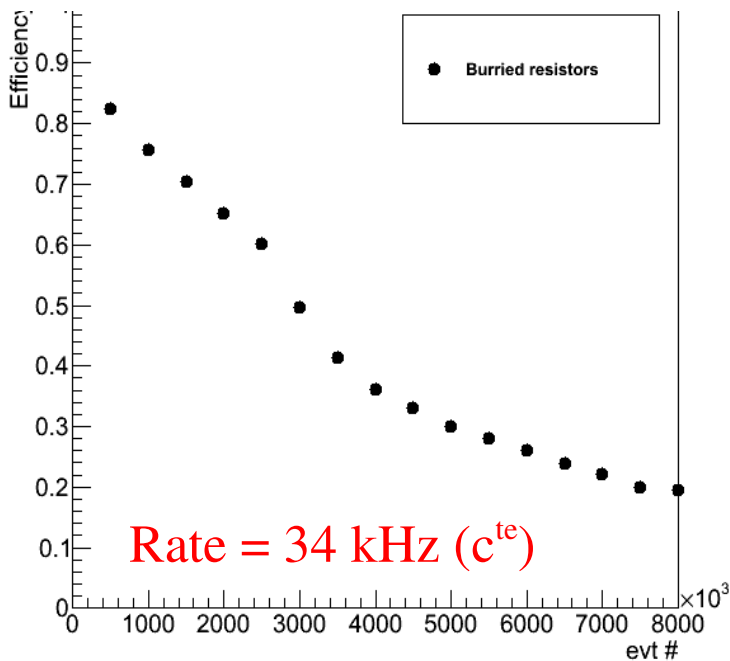
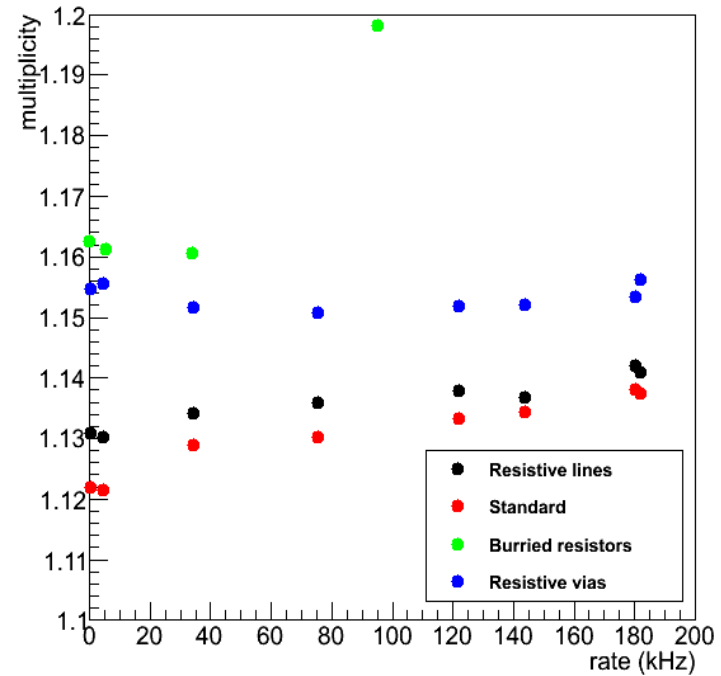
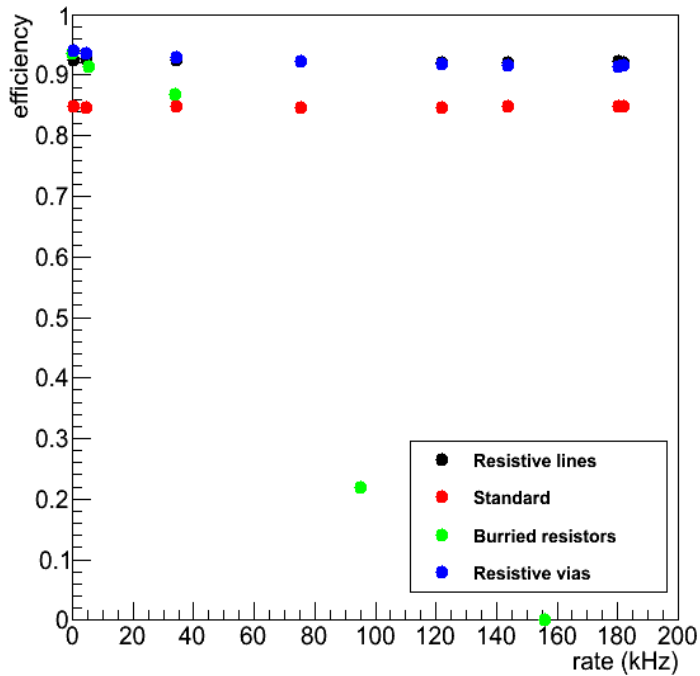


Buried resistors

Chb #	Mean value (%)	RMS (%)
2 (resistive lines)	91.3	2
3 (standard)	96.5	1.4
4 (resistive vias)	94.4	1.3
4 (buried resistors)	72.8	35.3

Homogenous response over the all active area within $\pm 2\%$ for all chambers except the buried resistors

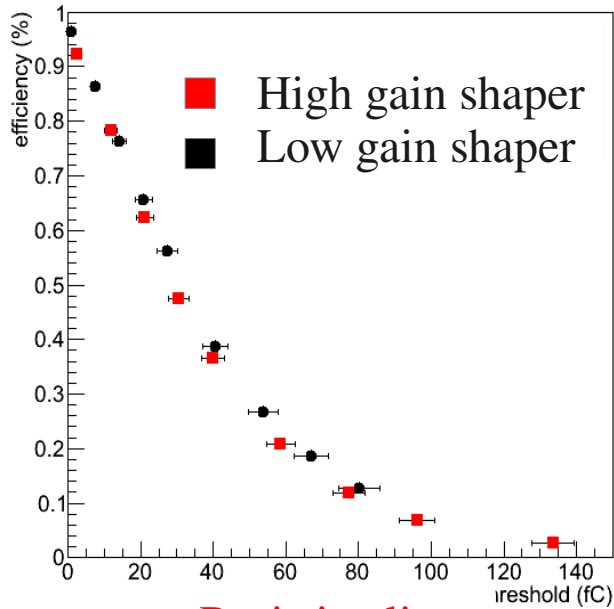
Rate capabilities



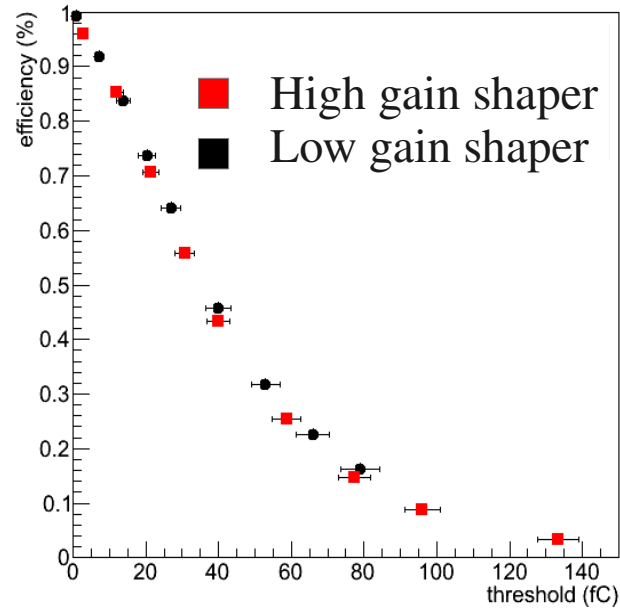
Efficiency and multiplicity remain constant from few kHz \rightarrow 200 kHz (except for burried resistors chamber that showed a charging up effect due to the construction default)

Low voltage (85% eff.) on the standard Micromegas to avoid crash of the DAQ @ high rate

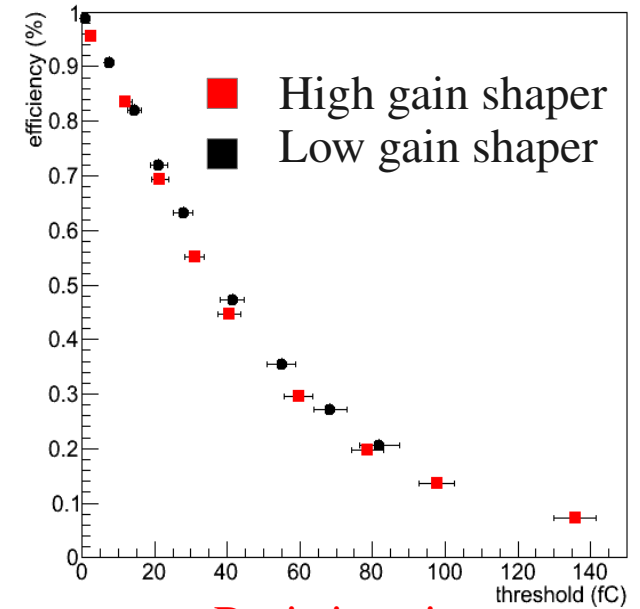
Threshold calibration



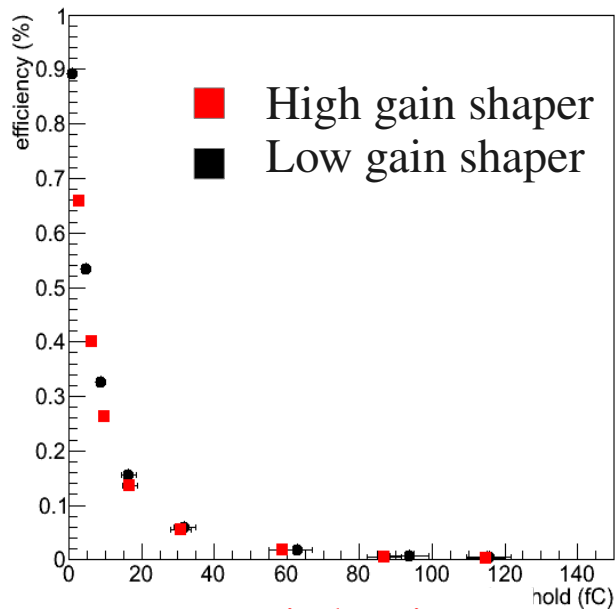
Resistive lines



Standard



Resistive vias



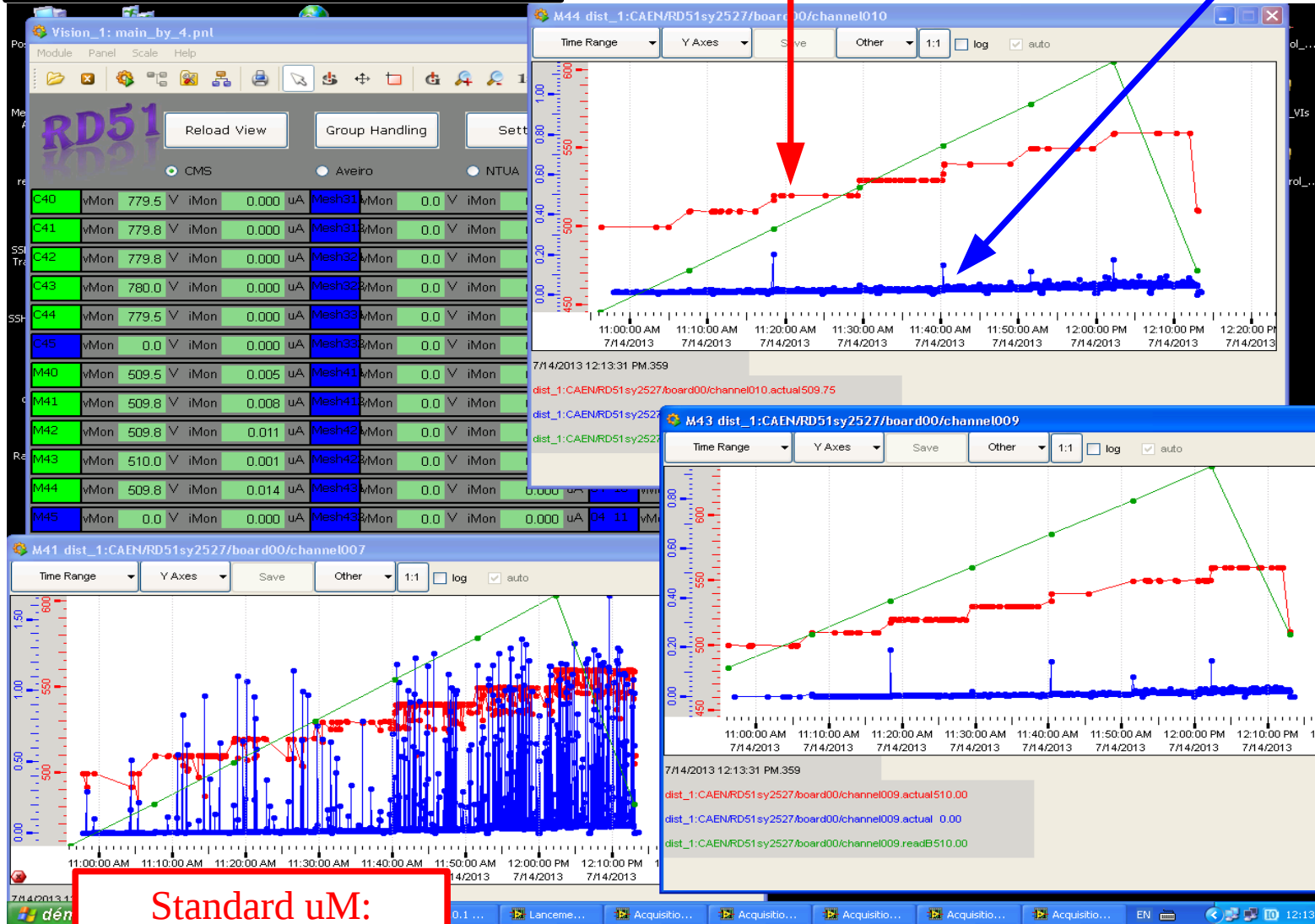
Buried resistors

For all chambers, trends superimpose → calibration factors (DAC/fC) OK

Spark rate

Spark study : increase V_{mesh} by step, look at current

Significant rate: 5 kHz / 4 cm²

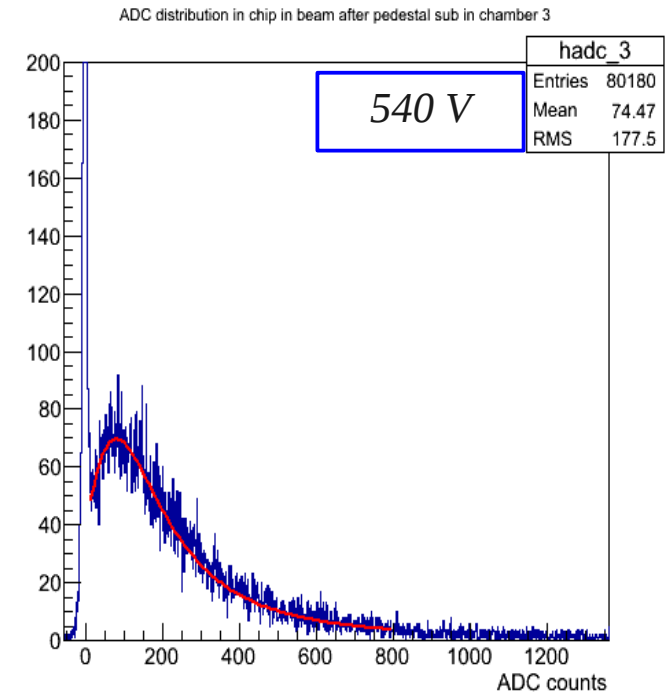
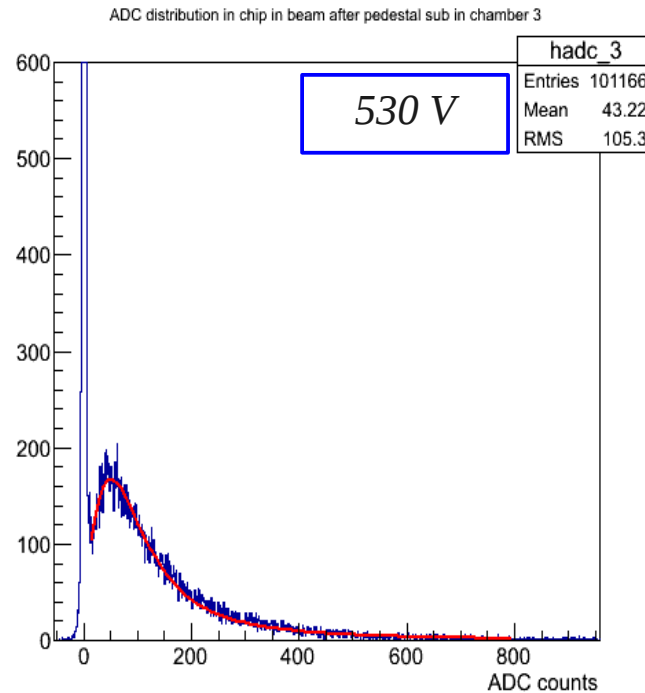
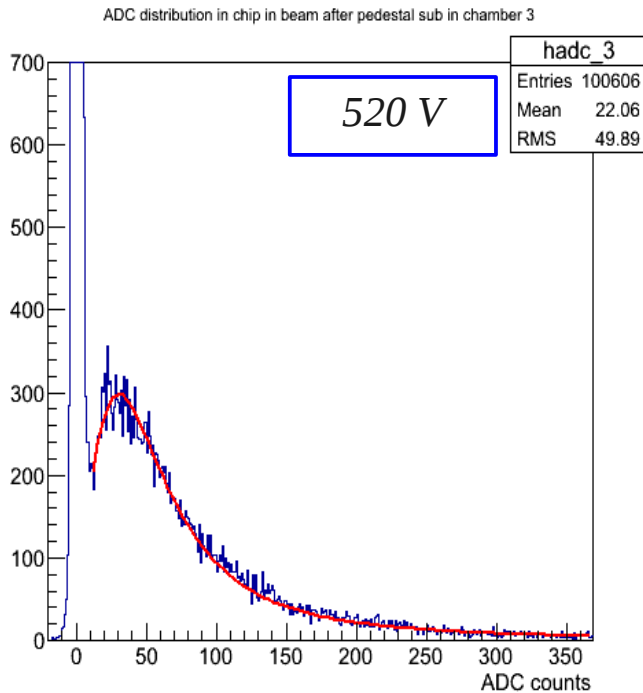


Resistive1 uM:
QUIET!

Resistive2 uM:
QUIET!

Standard uM:
WILD!

Analog readout



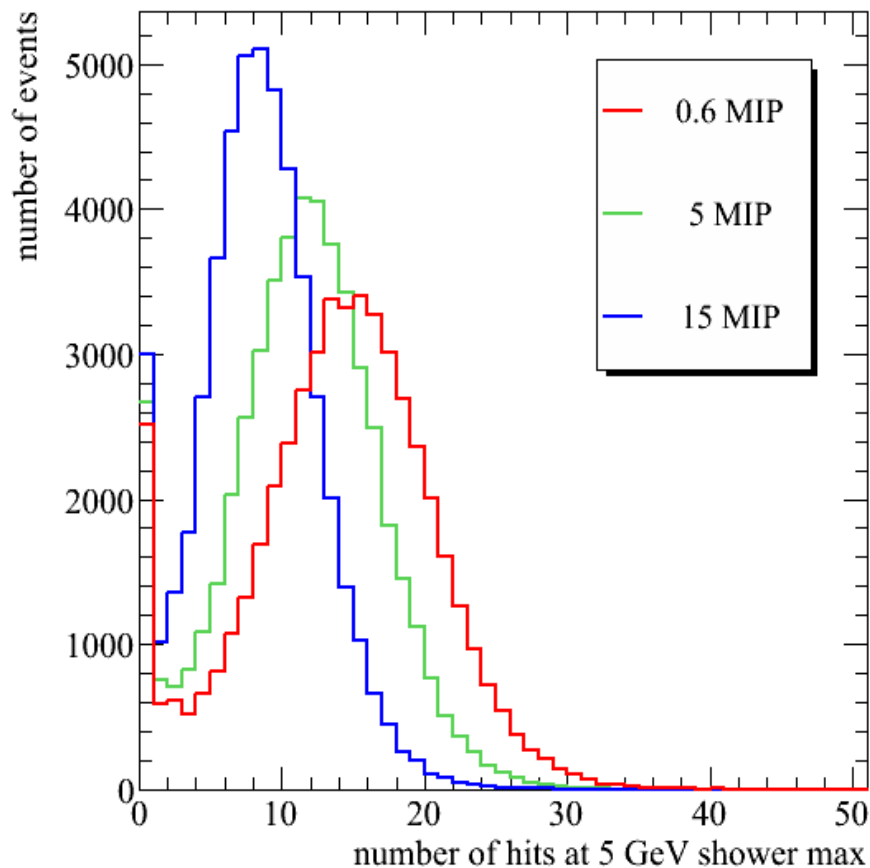
MIP measurements

*Very nice Landau distributions (pedestal will disappear after cut on digital info.)
Allows us to tune finely our threshold without any calibration constant*

Shower measurements

→ see next slides

EM showers (1/3)

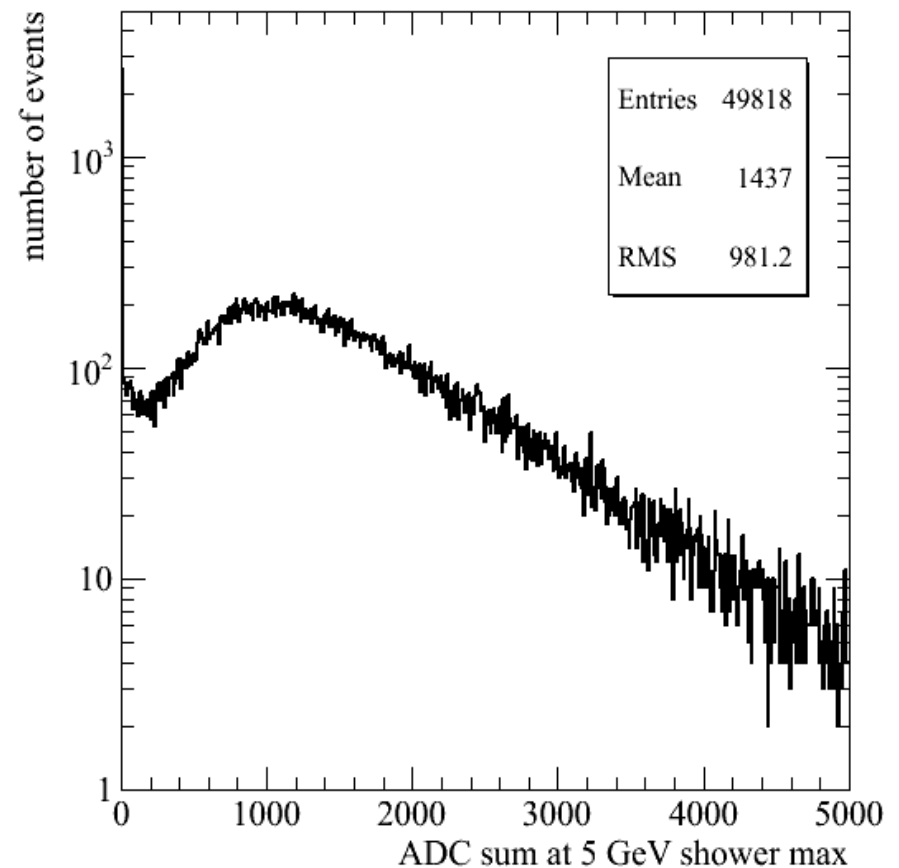


Digital response 1st chamber @ 5 GeV (7.2 cm absorber thickness)

Thr0 : mean value = 13.6 Nhits

Thr1 : mean value = 10.9 Nhits

Thr2 : mean value = 7.9 Nhits



Analog response 1st chamber @ 5 GeV (7.2 cm absorber thickness)

Mean signal = 1437 ADC

Steel thickness (cm)

0

1.8

3.6

5.4

7.2

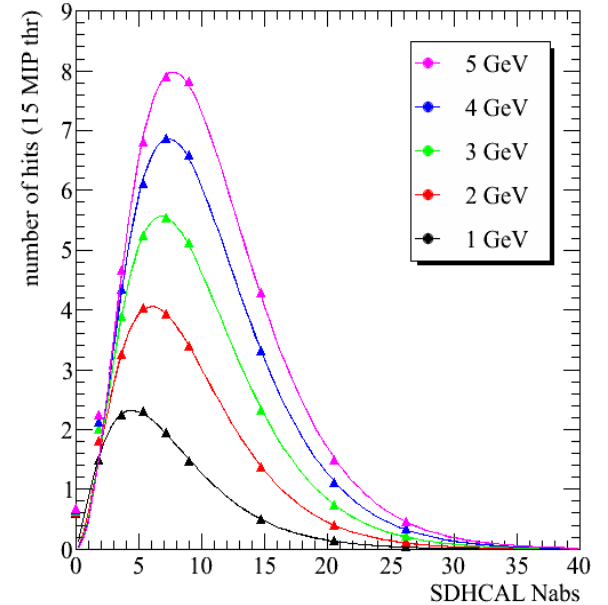
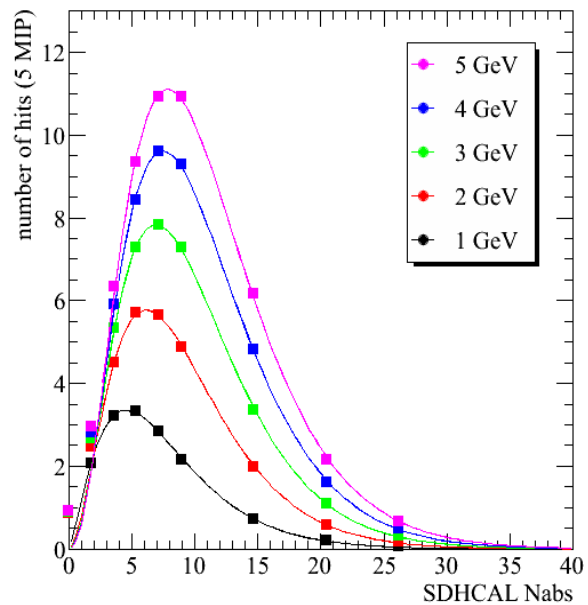
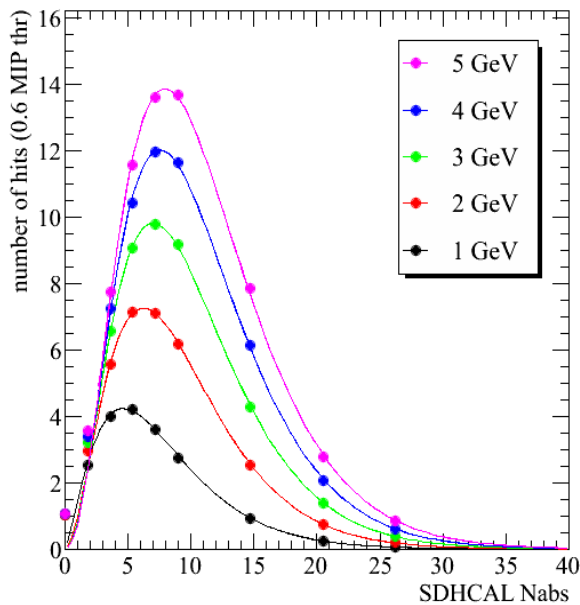
9

14.75

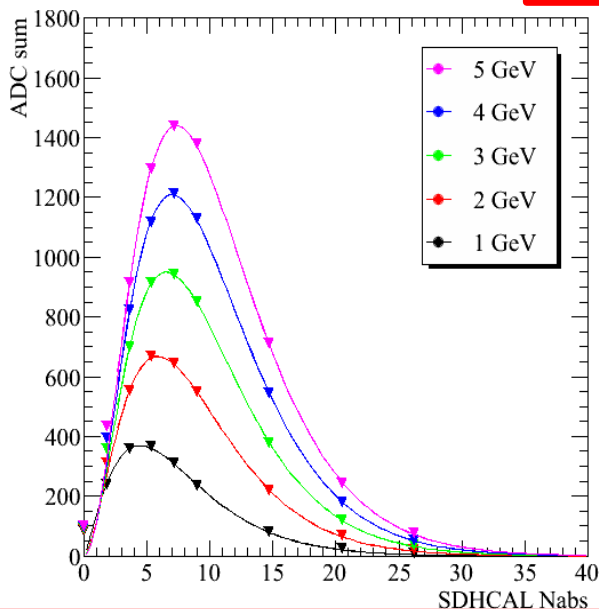
20.5

26.25

EM showers (2/3)



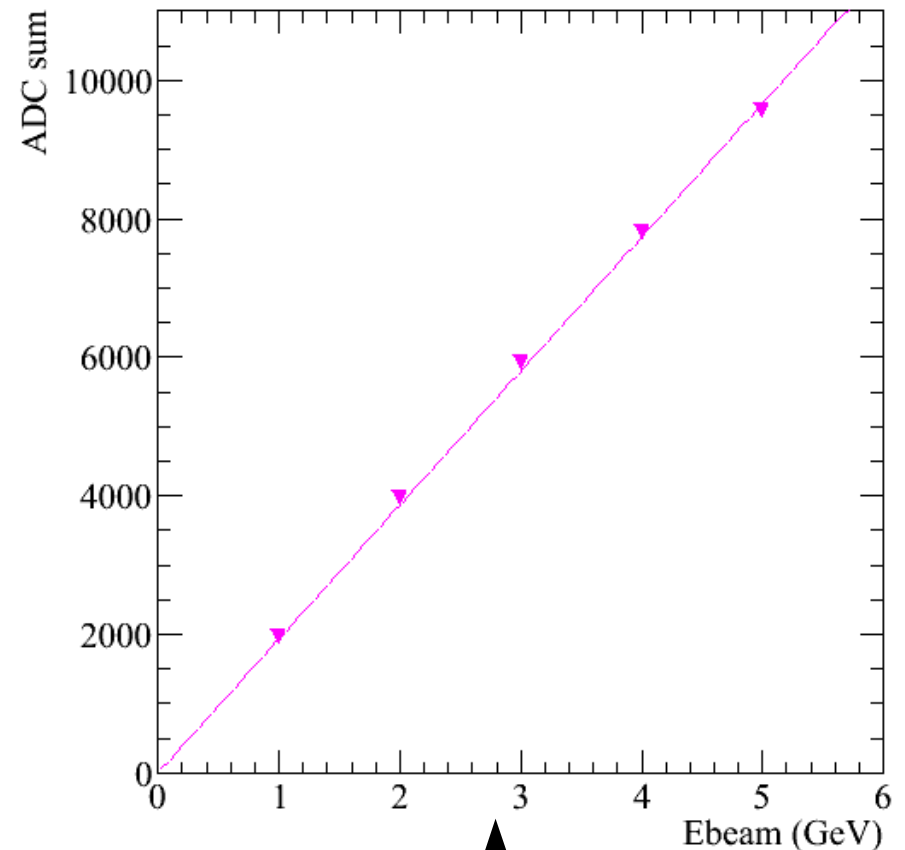
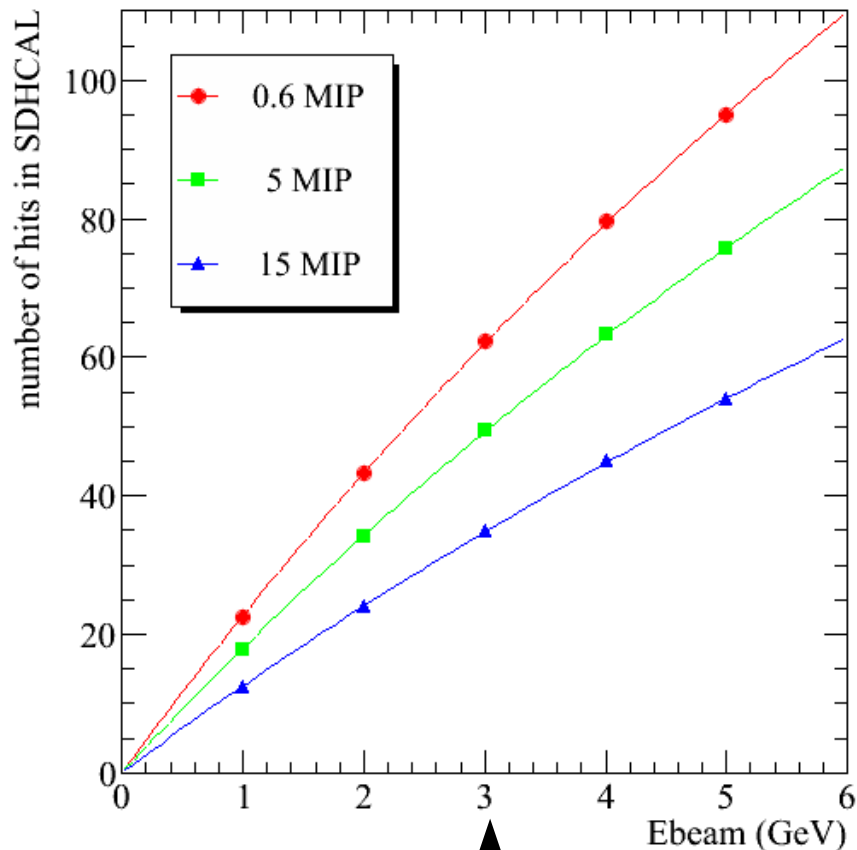
Digital EM shower longitudinal profile from 1 to 5 GeV



Analog and digital profiles → nice shapes
For both analog and digital profiles : Fit with $A \cdot x^B \cdot e^{-x/C}$
→ get the integrated response

Analog EM shower longitudinal profile from 1 to 5 GeV

EM showers (3/3)



Integrated profile

Response of a Micromegas SDHCAL to electrons :

- Digital response shows strong saturation
- Analog response almost fully linear

Conclusion

Resistive Micromegas → good physical performances
Efficiency $\geq 95\%$
Multiplicity $\in [1.03, 1.25]$
Rate capabilities until at least 50 kHz/cm^2
Response uniformity $\leq 2\%$
→ but also demonstrate their ability to face discharge without any damages on the R/O electronics, no voltage drop

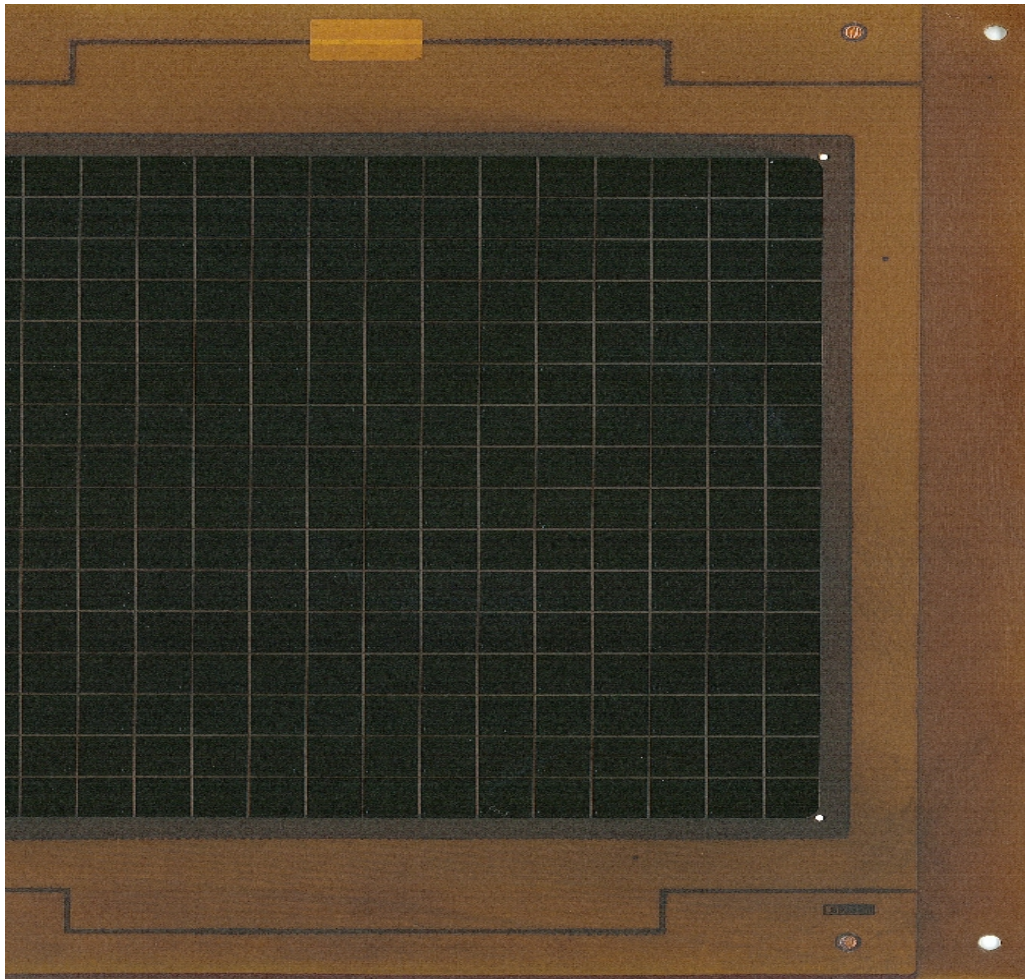
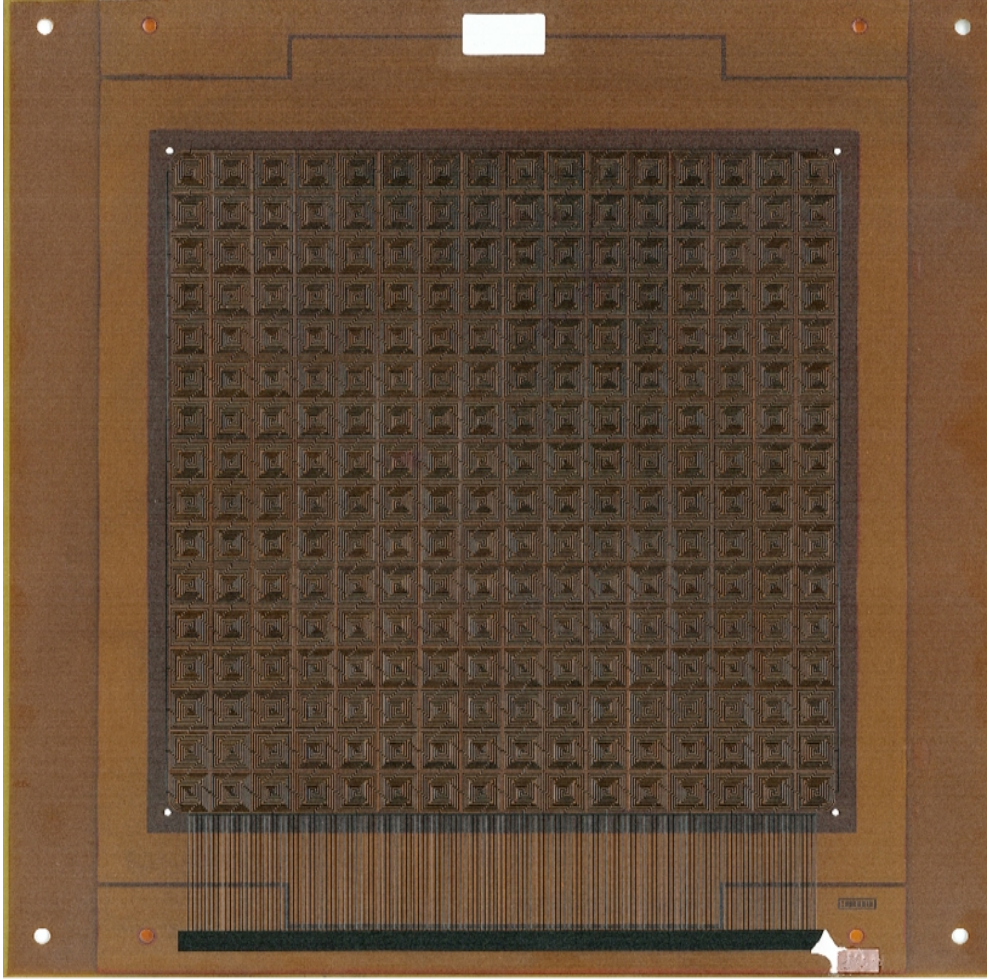
Configuration with burried resistors should be tested again with a correct construction to validate (or not ???) the principle

Thanks to DESY people for their help during the TB period :
Katja, Mathias, Ralf and Sam

The (dream ???) team



Back up slide



Back up slide

